



#### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

**Current** 

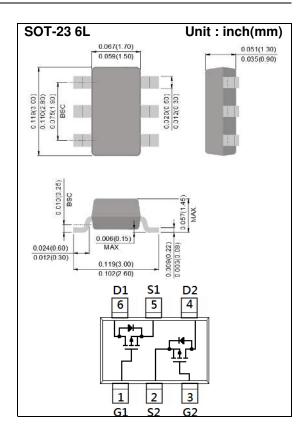
-3.2A

#### **Features**

- RDS(ON), VGS@-10V, ID@-3.2A<74mΩ
- RDS(ON), VGS@-4.5V, ID@-2.3A<83m $\Omega$
- RDS(ON), VGS@-2.5V, ID@-1.4A<115mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 12	V
Continuous Drain Current		ID	-3.2	Α
Pulsed Drain Current		I <sub>DM</sub>	-13	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient <sup>(Note 3)</sup>		Reja	100	°C/W





### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.5	-0.96	-1.3	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-3.2A	-	60	74	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.3A	-	67	83	
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.4A	-	84	115	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	Igss	V <sub>GS=±</sub> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-3.2A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	15	-	nC
Gate-Source Charge	Qgs		-	1.3	-	
Gate-Drain Charge	$Q_{gd}$		-	2	-	
Input Capacitance	Ciss	\/ 45\/ \/ 0\/	-	633	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,	-	50	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	35	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	3	-	
Turn-On Rise Time	tr	$V_{DD}$ =-15V, $I_{D}$ =-3.2A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega^{(Note 1,2)}$	-	43	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	223	-	
Turn-Off Fall Time	tf	RG=012(Note 1,2)	-	100	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.5	A
Diode Forward Current	Is		-		-1.5	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>G</sub> S=0V	-	-0.77	-1.2	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

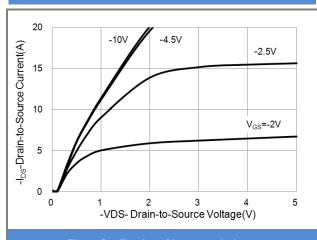


Fig.1 On-Region Characteristics

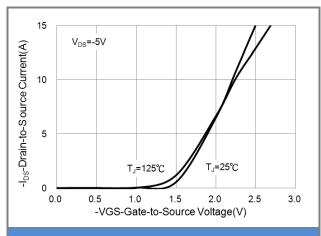


Fig.2 Transfer Characteristics

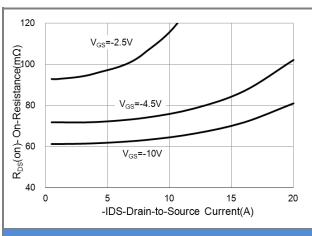


Fig.3 On-Resistance vs. Drain Current

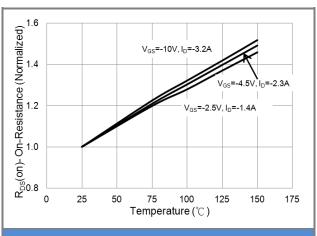
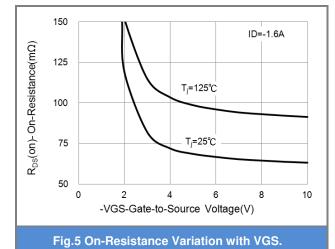
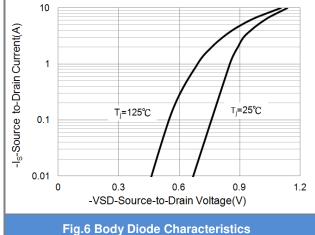


Fig.4 On-Resistance vs. Junction temperature









#### **TYPICAL CHARACTERISTIC CURVES**

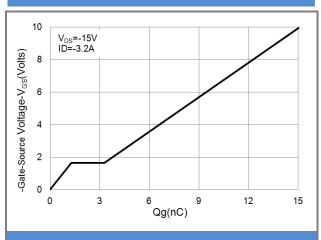


Fig.7 Gate-Charge Characteristics

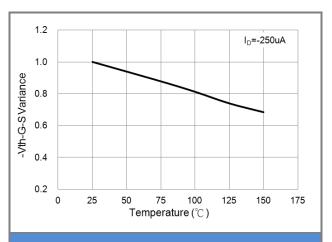


Fig.8 Threshold Voltage Variation with Temperature.

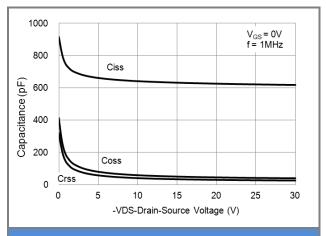


Fig.9 Capacitance vs. Drain-Source Voltage.

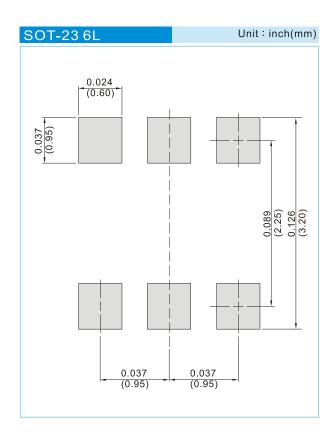




### PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6801_S1_00001	SOT-23 6L	3K pcs / 7" reel	ST1	Halogen free RoHS compliant
PJS6801_S2_00001	SOT-23 6L	10K pcs / 13" reel	ST1	Halogen free RoHS compliant

### **MOUNTING PAD LAYOUT**







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